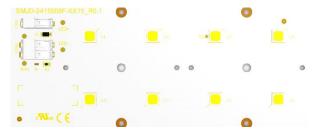
2x4 DC Module 5050

SMJD-2415008F-XX15













Product Brief

Description

- This Customized module is based on White Colored surface-mount LED comes in standard package dimension.
 - Package Size: 5.0x5.0x0.70mm
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

- High Intensity output and high luminance
- High Efficacy
- Compatible with 3rd party optics
- Lead free product
- RoHS compliant
- Comply with Zhaga Book 15

Key Applications

- Street Lighting
- Area Lighting
- Residential Lighting
- Urban Lighting



Table 1- Order Code

Nominal CCT (K)	CRI	Lens Type	Order Code
6500	70	-	SMJD-2415008F-XX1500C43A057ALL
5700	70	-	SMJD-2415008F-XX1500C43B057ALL
5000	70	-	SMJD-2415008F-XX1500C63C057ALL
4000	70	-	SMJD-2415008F-XX1500C63E057ALL
3000	70	-	SMJD-2415008F-XX1500C43G057ALL
2200	70	-	SMJD-2415008F-XX1500C19K057ALL

Revision History

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Performance Characteristics

Table 2. Electro Optical Characteristics, Tc =25°C, I_F= 650mA [1]

B		Value			11-2	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Mark
		2450	2630	-		C,E Rank
Luminous Flux	ΦV ^[2]	2260	2430	-	Lm	A,B,G Rank
		2040	2190	-]	K Rank
		-	175	-		C,E Rank
Luminous Efficiency	LPW	-	162	-	Lm/W	A,B,G Rank
		-	146	-]	K Rank
	сст	6000	6500	7000		A rank
		5300	5700	6000	. к	B rank
Correlated Color		4700	5000	5300		C rank
Temperature [3]		3700	4000	4200		E rank
		2900	3000	3200		G rank
		2100	2200	2300		K rank
CRI	Ra	70	-	-	-	
Color Consistency	SDCM	-	-	5	-	
Forward Voltage	Vin	21	23.1	25	Vdc	
Input Current	I _F	-	650	-	mA	
Power Consumption	Р		15.0		W	
Viewing Angle	2Θ1/2		120		deg.	

Notes:

- (1) The above data were tested at Tc=25°C.
- (2) Φ_{V} is the total luminous flux output measured with an integrated sphere, the tolerance is 7% .
- (3) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (4) To use the module properly, recommend to drive the module by a Constant Current Source (CCS). But the Maximum output voltage of the CCS should be limited by referring this datasheet.

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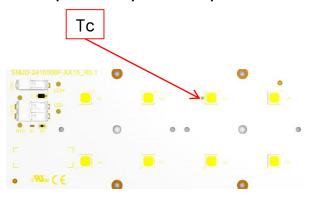


Absolute Maximum Ratings

Table 3. Absolute Maximum Ratings, I_F=650mA, Tc= 25°C (1)

Parameter	Symbol	Unit	Value	Remark
Power Consumption	Р	W	33.9	P_ _{Typ.} = 15.0W
Driving Current ⁽²⁾	I _F	mA	1400	I _{F_Typ.} = 650mA
Operating Temperature ⁽³⁾	T _c	°C	- 40 ~ 85	Reference point
Storage Temperature	T _{stg}	°C	- 40 ~ 100	With no power
ESD Sensitivity		10.7	±15	IEC Air
	-	KV -	±8	НВМ

ILLUSTRATION 1: How to predict components temperature (4)



Notes:

- (1) All guarantee are based on the Absolute Maximum Ratings listed.
- (2) Please use a Constant Current Source (CCS) to drive the module, the typical V_F of module is around 23.1VDC and $V_{F\ MAX}$ is around 25VDC, respectively.
- (3) Operating temperature was tested at the assigned Tc point on the PCB.
- (4) To ensure the module works properly, DO NOT let the Tc upper than 85 °C;

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Relative Spectral Distribution

Fig 1. Relative Spectral Distribution vs. Wavelength Characteristic

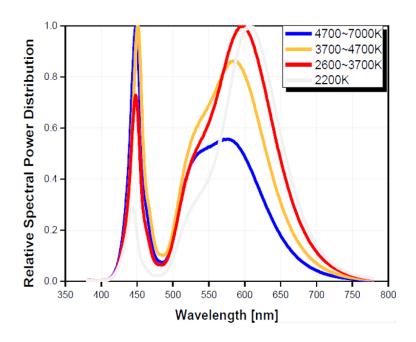
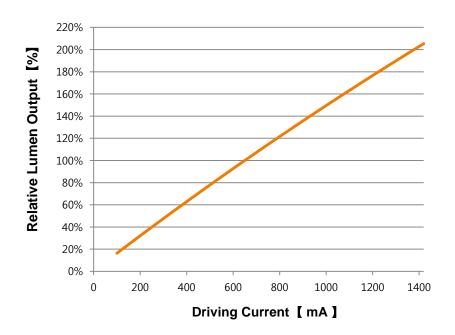


Fig 2. Forward Current vs. Relative Luminous Flux, Tc=25°C



Relative Spectral Distribution

Fig 3. Flux and Efficacy vs. Temperature at $T_c(at I_F=650mA)$

T _C [°C]	Flux[%]	Efficacy[%]
25	100	100
45	97	98
65	93	95
85	90	92

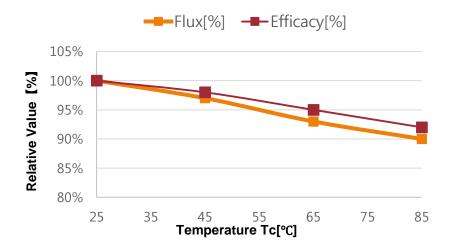
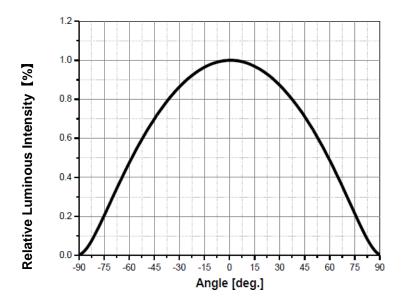
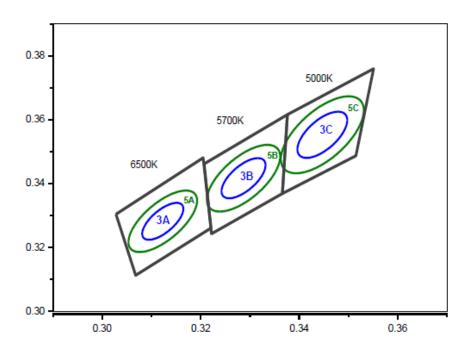


Fig 4. Typical Spatial Distribution



Angular Displacement [degrees]

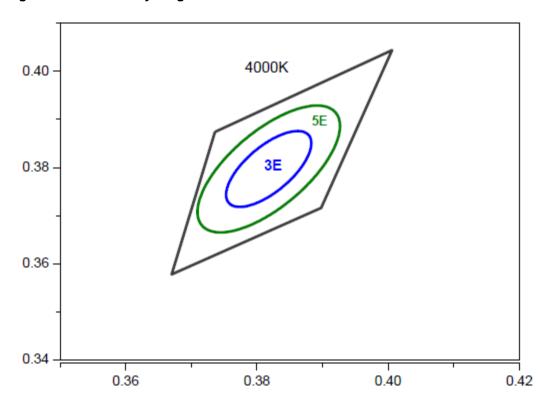
Fig 5. CIE Chromaticity Diagram



6500K 3Step		5700K 3Step		5000K 3Step	
;	3A	3B		;	3C
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
Major Axis a	0.0066	Major Axis a	0.0071	Major Axis a	0.0081
Minor Axis b	0.0027	Minor Axis b	0.003	Minor Axis b	0.0035
Ellipse	58	Ellipse	59	Ellipse	60
Rotation Angle	50	Rotation Angle		Rotation Angle	

	6500K 5Step		5700K 5Step		5000K 5Step	
5A		5B		5C		
	Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
	Major Axis a	0.0110	Major Axis a	0.0118	Major Axis a	0.0135
	Minor Axis b	0.0045	Minor Axis b	0.0050	Minor Axis b	0.0058
	Ellipse	58	Ellipse	59	Ellipse	60
	Rotation Angle	30	Rotation Angle	55	Rotation Angle	00

Fig 6. CIE Chromaticity Diagram



4000K 3Step

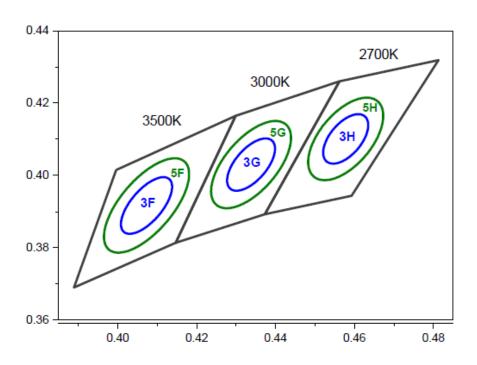
3E					
Center point	0.3818: 0.3797				
Major Axis a	0.00940				
Minor Axis b	0.00400				
Ellipse	53				
Rotation Angle	55				

4000K 5Step

5E				
Center point	0.3818 : 0.3797			
Major Axis a	0.0157			
Minor Axis b	0.0067			
Ellipse Rotation Angle	53			



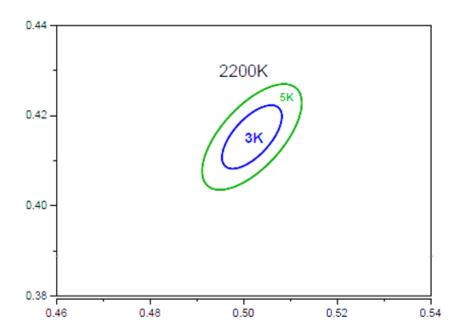
Fig 7. CIE Chromaticity Diagram



3500K 3Step		3000K 3Step		2700K 3Step		
3F		;	3G		3H	
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578: 0.4101	
Major Axis a	0.0093	Major Axis a	0.0085	Major Axis a	0.0079	
Minor Axis b	0.0041	Minor Axis b	0.0041	Minor Axis b	0.0041	
Ellipse Rotation Angle	53	Ellipse Rotation Angle	53	Ellipse Rotation Angle	54	

3500K 5Step		3000K 5Step		2700K 5Step	
5F		5G		5H	
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0155	Major Axis a	0.0142	Major Axis a	0.0132
Minor Axis b	0.0068	Minor Axis b	0.0068	Minor Axis b	0.0068
Ellipse Rotation Angle	53	Ellipse Rotation Angle	53	Ellipse Rotation Angle	54

Fig 8. CIE Chromaticity Diagram

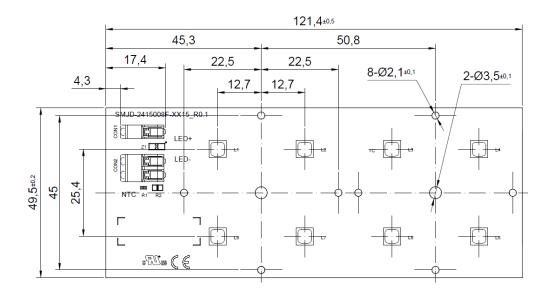


2200K 3Step				
3K				
Center point	0.5018: 0.4153			
Major Axis a	0.00863			
Minor Axis b	0.00398			
Ellipse Rotation Angle	49			

2200K 5Step							
5K							
Center point	0.5018 : 0.4153						
Major Axis a	0.01438						
Minor Axis b	0.00663						
Ellipse Rotation Angle	49						

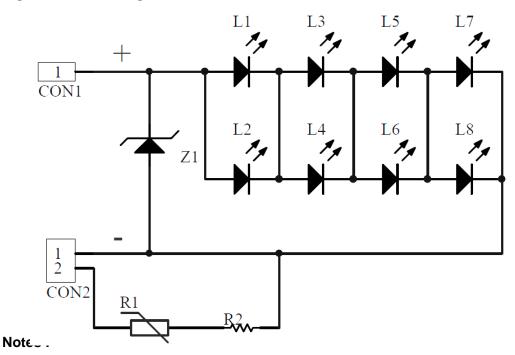
Mechanical Dimensions

Fig 9.mechanical dimensions



Circuit Drawing

Fig 10. circuit drawing

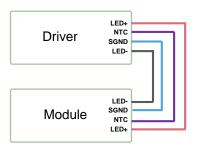


- (1) All dimensions are in millimeters.
- (2) Scale: None
- (3) Module thickness : 1.6 \pm 0.1

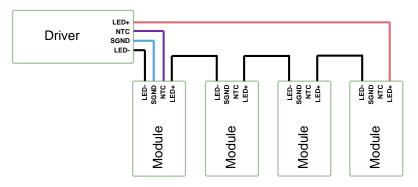


Application Information

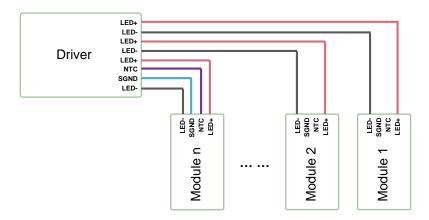
a). Connection between driver and module



b). Multiple module on one driver



c). To use a driver with multi output channels for group application



Notes:

(1) In case of all modules have to be in parallel for a group application, 3 is the max quantity in parallel.

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Application Information

a). Application

IP rating	No IP-rating
Over Temperature Detection	A resistor and NTC in series, where R=2KOhm, R _{NTC} =15K Ohm
Luminaire Class	IEC Class I and Class II
Dimming	Yes

Product Nomenclature

Product Name Rule:

^{2 ~ 7:} Refer to below table

	Volt	age			Pov	wer		LED Qty.			LED Custome Type (Free)			FREE					
	(2)			(3)				4	Ð				⑤		6	7	
	2		4		1		5		0		0		8		F		XX		15
0	0	0	0	0	0	0	0	0	0	0	0	0	0	F	5050	xx	Reference	15	Zhaga Book 15
1	10V	1	1V	1	10W	1	1W	1	100EA	1	10EA	1	1EA						
2	20V	2	2V	2	20W	2	2W	2	200EA	2	20EA	2	2EA						
3	30V	3	3V	3	30W	3	3W	3	300EA	3	30EA	3	ЗЕА						
9	90V	9	9V	9	90W	9	9W	9	900EA	9	90EA	9	9EA						
А	100V			А	100W			Α	1000EA										
В	110V			В	110W														
Z	350V			z	350W														

Comments Rule:

A B C

Lens Type		C	СТ	CRI		
4	4	E	3	С		
0	00		/0	70		
00	No lens		6500K	70	CRI70	
		Wo	5700K	80	CRI80	
			5000K			
		WN	4000K			
		ww	3000K			
			2200K			

①: SMJD - Seoul Outdoor Module

Product Nomenclature

Characteristics Rule:

00 C63 E05 7 All A B C D E

Lens	s type Flux bin		CCT bin		CR	l bin	VF Bin ⁽¹⁾		
	Α	ı	В	С		D		Е	
(00	С	63	E	E05		7	ALL	
00	No lens	C63	2630 lm	A05	6500K 5-step	7	CRI70	ALL	VF: ALL
		C43	2430 lm	B05	5700K 5-step	8	CRI70		
		C19	2190 lm	C05	5000K 5-step				
				E05	4000K 5-step				
				G05	3000K 5-step				
				K05	2200K 5-step				

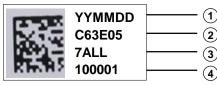
Marking Information

Fig 11. Marking Point



Marking point

QR Code Information



		QR Code Information						
Items	Factory	SAP Code	SMT Date	Rank Information	Line No.	Lot No.	Product	Notes
Digits	1 Digit	7 Digit	6 Digit	10 Digit	1 Digit	1 Digit	5 Digit	In Total
Information	*	*****	YYMMD D	C63E05 7ALL	1~9, A~Z	1~9, A~Z	00001	31 Digits

Plain Code Information

No.	Item	Information		Digits	Remark												
1	Date	YYMMDD		YYMMDD		YYMMDD		YYMMDD		YYMMDD		YYMMDD		YYMMDD		6Digit	SMT date
		C63			C63=2630lm												
	Flux ⁽¹⁾		C43	3Digit	C43=2430lm												
(2)	2		C19		C19=2190lm												
	CCT	X05 5- step		3Digit	X=A,B,C,E,G,K												
	CRI		7	1Dight	CRI=70												
3	CRI		8	1Dight	CRI=80												
	V _F	ALL		ALL		3Digit	VF: ALL										
	Lot No.	1		1		1 Digit	0~9,A~Z										
4	Sequence No.	00001		5 Digit	00001 ~ 99999												

Notes:

This product 5-step mixing can use different flux Bin

(1) Module Flux code rule as below table

Symbol	lm	Symbol	lm	Symbol	lm	Symbol	lm
D91	3910	O50	14500	R50	17500	U50	20500
M20	12200	P50	15500	S50	18500	V20	21200
N00	13000	Q50	16500	T50	19500	W00	22000



Label Information

PO Number	XXXXXX (1)
Part Number	SMJD-2415008F-XX1500C63E057ALL (2)
Bin Code	C63E057ALL (3)
Quantity	XX
Country of Origin	XX ⁽⁴⁾
Date Code	YYYYWW (5)
Lot Code	YYMDDXXXXX- XXXXXXX (6)
SEOUL	SEOUL SEMICONDUCTOR CO.,LTD.

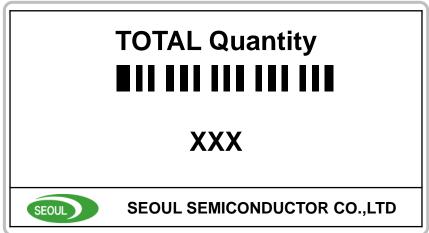
Notes

- (1) This is customer's PO Number
- (2) Please refer to SPEC page 15 (30 digit code)
- (3) Please refer to SPEC page 16
- (4) Country of Origin: 2 digit code . For example : Chinese Code: CN
- (5) Date Code: YYYYWW: Packing Date: Year + Week
- (6) Lot Code:

Initial of manufacture is refer to the 2D code rule. YYMDD: Packing Date (Oct.: A, Nov.: B, Dec.: C)

X : Initial of Manufacturer XXXX : Sealing Pack No. XXXXXXX : SSC SAP Code

(7) It is attached to the top left corner of the box.

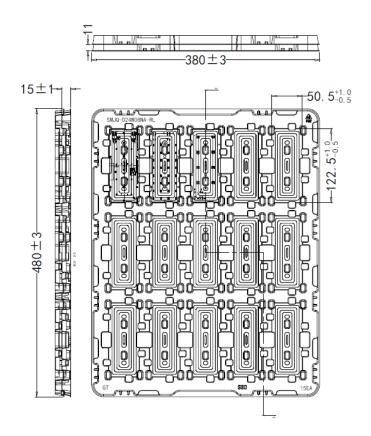


Notes

(1) It is attached to the bottom right corner of the carton box.

Packaging Specification

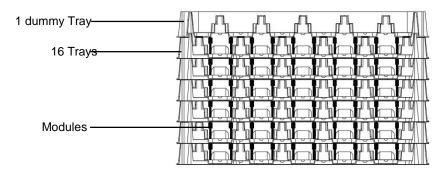
1. Tray information



Notes:

- (1) Quantity: 15 pcs/Tray
- (2) All dimensions are in millimeters (tolerance : ± 0.3)
- (3) Scale none

2. Tray stack and taping



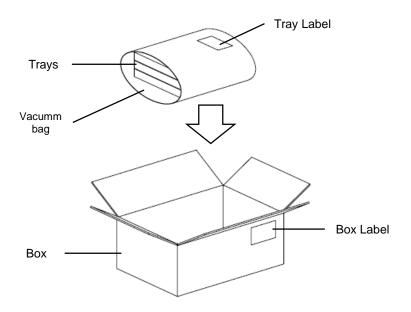
Notes:

(1) 16 Trays and additional 1 dummy tray up of box



Packaging Specification

3. Box information & packing

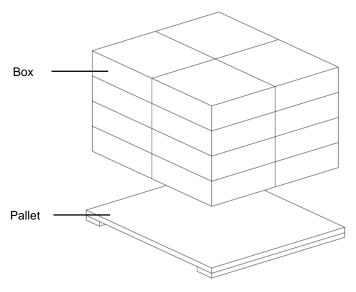


Notes:

(1) Quantity: 16Trays (16*15=240pcs) / Box

(2) Box size: 495*395*209 mm

4. Pallet information & packing



Notes:

(1) Quantity: 1 Pallet = 30(6*5) Boxes = 480(30*16) Trays = 7200(480*15) Modules

(2) Pallet size: 1300*1130*12.5mm



Precaution for Use

- (1) Check the appearance of module before wiring/ assembly, DO NOT use the LED cracked or PCB damaged module.
- (2) The module was designed to be driven with DC source, recognize the polarities of the module was necessity.
- (3) It was SELV module, DO NOT connect the LED directly to main power during wiring.
- (4) DO NOT let the LED packages contacted with any hard matters.
- (5) There was no current regulator built in module, unevenly load between different parallel modules may occur due to the modules V_F variance.
- (6) Please do not use together with the materials containing Sulfur.
- (7) Please do not make any modification on module.



Precaution for Use

- (8) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).

 Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event: One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls

- Humidity control (ESD gets worse in a dry environment)

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device.

The effects from an EOS event can be noticed through product performance like:

Changes to the performance of the LED package (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)

Changes to the light output of the luminaire from component failure

Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures

It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred.

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse).
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope).
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing
 - qualified LED driver with no big over shoot out put
 - Isolated driver that to prevent harmful peaks passed to module.
 - A current limiting device



Storage before use

- (1) Do not impact or place pressure on this product because even a small amount of pressure can damage the product. The product should also not be placed in high temperatures, high humidity or direct sunlight since the device is sensitive to these conditions.
- (2) When storing devices for a long period of time before usage, please following these guidelines:
 * The devices should be stored in the anti-static bag that it was shipped in from Seoul-Semiconductor with opening.
 - * If the anti-static bag has been opened, re-seal preventing air and moisture from being present in the bag.



Guidelines for properly working with Module

- (1) Discharge the lighting system a minimum of 2-3 times prior to working with the module.
- (2) Use only properly rated test equipment and tools for the rated voltage and current of the product being tested.
- (3) It is strongly suggested to wear rubber insulated gloves and rubber bottom shoes.
- (4) Do not wear any conductive items (such as jewelry) which could accidentally contact electric circuits
- (5) Perform several tests with power off and the lighting system unplugged.
- (6) Faults, lightning, or switching transients can cause voltage surges in excess of the normal ratings.
- (7) Internal component failure can cause excessive voltages.
- (8) Stored or residual electricity in long wire could be hazardous.
- (9) Make sure proper discharge prior to starting work.



Company Information

Published by

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Company Information

Seoul Semiconductor (SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", deep UV LEDs, "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs. The company's broad product portfolio includes a wide array of package and device choices such as Acrich, high-brightness LEDs, mid-power LEDs, side-view LEDs, through-hole type LED lamps, custom displays, and sensors. The company is vertically integrated from epitaxial growth and chip manufacture in it's fully owned subsidiary, Seoul Viosys, through packaged LEDs and LED modules in three Seoul Semiconductor manufacturing facilities. Seoul Viosys also manufactures a wide range of unique deep-UV wavelength devices.

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Revision History

Revision	Date	Page	Remarks
R0.1	2019.09.25	All	Preliminary data sheet for SMJD-2415008F-XX15
R0.2	2019.09.29	5	Update the maximum current
R0.3	2019.10.21	All	Add 2200K parameter